

Fourth Semester B.E. Degree Examination, June/July 2017
Power Electronics

Time: 3 hrs.

Max. Marks:100

Note: Answer FIVE full questions, selecting at least TWO questions from each part.**PART – A**

- 1 a. List and explain the different types of power electronic converters. Show their I/O characteristics. (08 Marks)
- b. What are the peripheral effects of power converters? (04 Marks)
- c. What is the necessity of base drive control high power transistor? Explain proportional base and anti-saturation control. (08 Marks)
- 2 a. With necessary waveforms. Explain the switching performance of power BJT. (07 Marks)
- b. With relevant diagrams, discuss the methods of providing isolation of Gate/base drive control in power circuits and what are its limitation? (07 Marks)
- c. In the power BJT circuit has β in the range of 10 to 25. If $V_{CC} = 230V$, $R_c = 12\Omega$, $V_{BB} = 15V$, $V_{CES} = 1.2V$ and $V_{BES} = 1.8V$. Calculate :
 - i) The value of R_B required to move the transistor into saturation with an ODF of 6.
 - ii) Forced beta β_f
 - iii) Total power dissipation. (06 Marks)
- 3 a. With a neat sketch, explain the static VI characteristics of an SCR. What are the significances? Define the latching current, holding current and break over voltage. (08 Marks)
- b. With the help of two transistor model of an SCR, Derive the expression of anode current. Explain the switching action and significance of the Gate control. (08 Marks)
- c. The SCR in the circuit of Fig Q3(c) has a latching current of 50mA and is triggered by a gate pulse width 50 μ .sec. Show that without resistance R^1 thyristor will fail to remain ON when the gating pulse ends. Also find the maximum value of R^1 to ensure firing. The ON state voltage drop of an SCR can be neglected. (04 Marks)

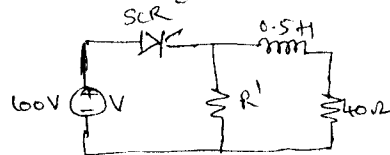


Fig Q3 (c)

- 4 a. Define commutation? What are the necessary conditions of commutation? Mention the different types of commutation circuits. (08 Marks)
- b. With necessary circuit and waveforms, explain complementary commutation scheme. Derive an expression for t_c . (08 Marks)
- c. The circuit of Fig Q4(c) employing class -C commutation has $V_s = 200V$, $R_1 = 10\Omega$, $R_2 = 100\Omega$. Determine :
 - i) Peak value of the current through T_1
 - ii) Value of capacitor C, if each thyristor has turn off time of 40 μ .sec. Take factor of safety as 2. (04 Marks)

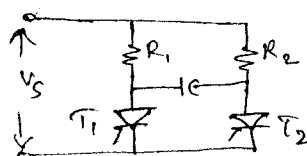


Fig Q4(c)

PART – B

- 5 a. What is the use of freewheeling diode in the converters? Explain the principle of operation of single phase FWR feeding with R-L loads. Draw the relevant sketch and waveforms. (07 Marks)
- b. With neat circuit and waveforms, explain the working of three phase half wave converter. Derive the expression for $V_o(av)$ for resistive load. (07 Marks)
- c. In the three phase half wave converter has a line – line voltage of 415V, 50Hz, the load is purely resistive load with $R = 15\Omega$. If the average load voltage is 50% of maximum possible average output voltage. Determine :
 i) The delay angle α
 ii) Average values of output current
 iii) The average and rms values of thyristor current. (06 Marks)
- 6 a. What is chopper? Classify the different types of choppers with circuit diagrams. (06 Marks)
- b. With the help of circuit and quadrilateral diagrams, explain the working of a class B chopper. Mention the devices that give path for the current in each quadrant. (08 Marks)
- c. In the chopper circuit of Fig Q6(c). The average output voltage is 109V. The voltage drop across the chopper switch when it is ON i.e. $V_s = 2V$. If the load resistance $R = 10\Omega$, $f = 1.5$ KHz and duty ratio $\delta = 50\%$. Calculate :
 i) The rms output voltage
 ii) The dc input to the chopper
 iii) Chopper efficiency
 iv) Input resistance of chopper. (06 Marks)

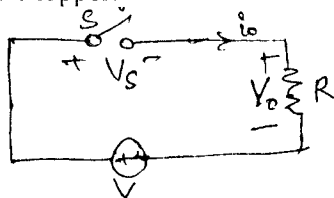


Fig Q6(c)

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